



# HiPerFRED $V_{RRM} = 400 V$ $I_{FAV} = 10 A$

 $t_{rr} = 45 \, \text{ns}$ 

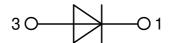
High Performance Fast Recovery Diode Low Loss and Soft Recovery Single Diode

Part number

#### **DPG10I400PA**



Backside: cathode



#### Features / Advantages:

- Planar passivated chips
- Very low leakage current
  Vary about reasons times
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

#### **Applications:**

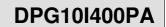
- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

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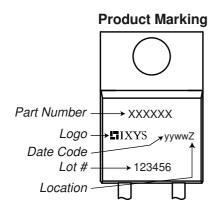


<b>Fast Dio</b>	de				Ratings	S	
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse blockir	ng voltage	$T_{VJ} = 25^{\circ}C$			400	V
V <sub>RRM</sub>	max. repetitive reverse blocking vo	oltage	$T_{VJ} = 25^{\circ}C$			400	V
IR	reverse current, drain current	$V_R = 400 \text{ V}$	$T_{VJ} = 25^{\circ}C$			1	μΑ
		$V_R = 400 V$	$T_{VJ} = 150$ °C			0.15	mA
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 10 A	$T_{VJ} = 25^{\circ}C$			1.32	V
		$I_F = 20 A$				1.51	٧
		I <sub>F</sub> = 10 A	T <sub>VJ</sub> = 150°C			1.03	V
		$I_F = 20 A$				1.24	٧
I FAV	average forward current	T <sub>C</sub> = 150°C	T <sub>vJ</sub> = 175°C			10	Α
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage		T <sub>VJ</sub> = 175°C			0.77	V
$\mathbf{r}_{F}$	slope resistance	ss calculation only				19.8	mΩ
R <sub>thJC</sub>	thermal resistance junction to case	)				2.3	K/W
R <sub>thCH</sub>	thermal resistance case to heatsin	k			0.5		K/W
P <sub>tot</sub>	total power dissipation		$T_C = 25^{\circ}C$			65	W
I <sub>FSM</sub>	max. forward surge current	$t = 10 \text{ ms}$ ; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			150	Α
CJ	junction capacitance	$V_R = 200 V$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		12		pF
I <sub>RM</sub>	max. reverse recovery current		$T_{VJ} = 25 ^{\circ}\text{C}$		4		Α
		$I_F = 10 \text{ A}; V_R = 270 \text{ V}$	$T_{VJ} = 125$ °C		6		Α
t <sub>rr</sub>	reverse recovery time	$\begin{cases} I_F = 10 \text{ A; } V_R = 270 \text{ V} \\ -di_F /dt = 200 \text{ A/} \mu \text{s} \end{cases}$	$T_{VJ} = 25 ^{\circ}\text{C}$		45		ns
	)		$T_{VJ} = 125^{\circ}C$		65		ns





Package	e TO-220			Ratings	s	
Symbol	Definition	Conditions	min.	typ.	max.	Unit
RMS	RMS current	per terminal			35	Α
T <sub>vJ</sub>	virtual junction temperature		-55		175	°C
T <sub>op</sub>	operation temperature		-55		150	°C
T <sub>stg</sub>	storage temperature		-55		150	°C
Weight				2		g
M <sub>D</sub>	mounting torque		0.4		0.6	Nm
F <sub>c</sub>	mounting force with clip		20		60	N



### Part description

D = Diode

P = HiPerFRED

G = extreme fast

10 = Current Rating [A]

I = Single Diode

400 = Reverse Voltage [V]

PA = TO-220AC (2)

C	Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
5	Standard	DPG10I400PA	DPG10I400PA	Tube	50	506654

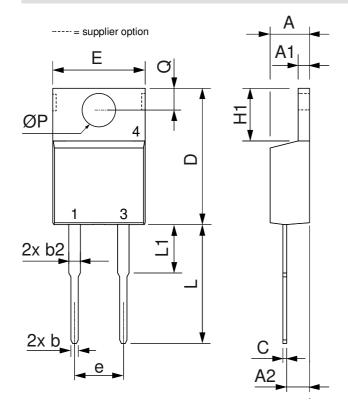
Similar Part	Package	Voltage class	
DPG10I400PM	TO-220ACFP (2)	400	

<b>Equivalent Circuits for Simulation</b>			* on die level	$T_{VJ} = 175^{\circ}C$
$I \rightarrow V_0$		Fast Diode		
V <sub>0 max</sub>	threshold voltage	0.77		V
R <sub>0 max</sub>	slope resistance *	16.6		mΩ





## Outlines TO-220



Dim.	Millimeter		Incl	nes
	Min.	Max.	Min.	Max.
Α	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
С	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
е	5.08	BSC	0.200	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125

